TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74AC109P, TC74AC109F

Dual J-K Flip Flop with Preset and Clear

The TC74AC109 is an advanced high speed CMOS DUAL J- \overline{K} FLIP FLOP fabricated with silicon gate and double-layer metal wiring C²MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

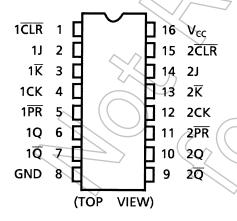
In accordance with the logic level given J and \overline{K} input this device changes state on positive going transition of the clock pulse. \overline{CLEAR} and \overline{PRESET} are independent of the clock and accomplished by a low logic level on the corresponding input.

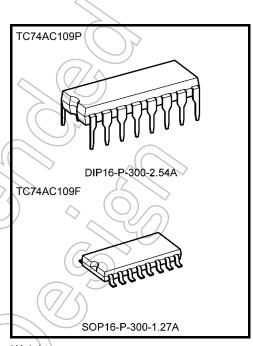
All inputs are equipped with protection circuits against static discharge or transient excess voltage.

Features

- High speed: $f_{max} = 200 \text{ MHz}$ (typ.) at $V_{CC} = 5 \text{ V}$
- Low power dissipation: $I_{CC} = 4 \mu A$ (max) at $T_a = 25$ °C
- High noise immunity: V_{NIH} = V_{NIL} = 28% V_{CC} (min)
- Symmetrical output impedance: $|I_{OH}| = I_{OL} = 24$ mA (min) Capability of driving 50 Ω transmission lines.
- Balanced propagation delays: $t_{pLH} \simeq t_{pHL}$
- Wide operating voltage range: V_{CC} (opr) = 2 to 5.5 V
- Pin and function compatible with 74F109

Pin Assignment



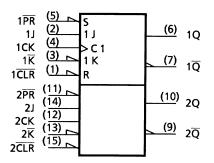


Weight

DIP16-P-300-2.54A SOP16-P-300-1.27A

: 1.00 g (typ.) : 0.18 g (typ.)

IEC Logic Symbol

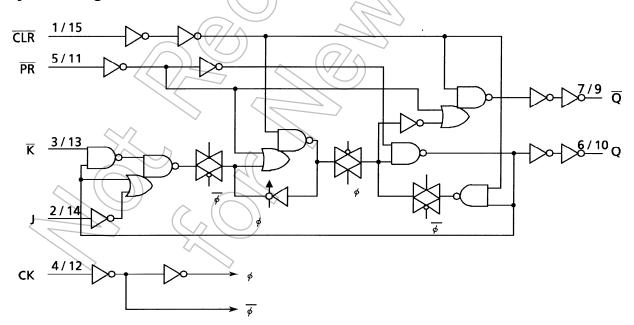


Truth Table

	Inputs					puts	Function	
CLR	PR	J	K	СК	Q	Q	Function	
L	Н	Х	Х	Х	L	Н	Clear	
Н	L	Х	Х	Х	Н	L	Preset	
L	L	Х	Х	Х	Н	Н		
Н	Н	L	Н		Qn	\overline{Q}_n	No Change	
Н	Н	L	L		L	Н		
Н	Н	Н	Н		Н	L		
Н	Н	Н	L		\overline{Q}_n	Qn	Toggle	
Н	Н	Х	Х		Qn	\overline{Q}_n	No Change	

X: Don't care

System Diagram



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Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V _{CC}	−0.5 to 7.0	V
DC input voltage	V _{IN}	-0.5 to V _{CC} + 0.5	V
DC output voltage	V _{OUT}	-0.5 to V _{CC} + 0.5	⟨v
Input diode current	lik	±20	mA
Output diode current	I _{OK}	±50	mA
DC output current	lout	±50	mA
DC V _{CC} /ground current	Icc	±100	_mA
Power dissipation	PD	500 (DIP) (Note 2)/180 (SOP)	mW
Storage temperature	T _{stg}	-65 to 150	°C °C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: 500 mW in the range of Ta = -40 to 65°C. From Ta = 65 to 85°C a derating factor of -10 mW/°C should be applied up to 300 mW.

Operating Ranges (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	VCC	2.0 to 5.5	V
Input voltage	// ŷ _{IN}	0 to V _{CC}	V
Output voltage	Vout	0 to V _{CC}	٧
Operating temperature	Topr	-40 to 85	°C
Input rise and fall time	dt/dV	0 to 100 ($V_{CC} = 3.3 \pm 0.3 \text{ V}$) 0 to 20 ($V_{CC} = 5 \pm 0.5 \text{ V}$)	ns/V

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either V_{CC} or GND.



Electrical Characteristics

DC Characteristics

Characteristics	Symbol	Test Condition V _{CC}		Ta = 25°C			Ta = −40 to 85°C		Unit		
Onaraciensiics	Cymbol				Min	Тур.	Max	Min	Max	J	
				2.0	1.50	_ `	1	1.50	_		
High-level input voltage	V_{IH}		_	3.0	2.10	_		2.10	_	V	
				5.5	3.85	_	1	3.85	_		
Law laval is suit		_		2.0	_	(0	0.50	_	0.50		
Low-level input voltage	V_{IL}			3.0	-	1	0.90	_	0.90	V	
			,	5.5	-(7/	1.65	_	1.65		
	V _{ОН}			2.0	1.9	2.0	_	1.9	_		
		V _{IN} = V _{IH} or V _{IL}	$I_{OH} = -50 \mu A$	3.0	2.9	3.0	_	2.9	_		
High-level output				4.5	4.4	4.5	/	4.4	>	V	
voltage			$I_{OH} = -4 \text{ mA}$	(3.0)	2.58		-6	2.48	> —		
			I _{OH} = -24 mA	4.5	3.94	_<		3.80) —		
			$I_{OH} = -75 \text{ mA}$ (Note)	5.5		_	1	3.85			
	V _{OL}			2.0	_	0.0	0.1	<u> </u>	0.1		
		ļ.,	$I_{OL} = 50 \mu A$	3.0	_	0.0	0.1	_	0.1		
Low-level output		V _{IN} = V _{IH} or V _{IL}		4.5	_	0.0/	0.1	_	0.1	V	
voltage			I _{OL} = 12 mA	3.0			0.36	_	0.44		
			I _{OL} = 24 mA	4.5	-	//-	0.36	_	0.44		
			$I_{OL} = 75 \text{ mA}$ (Note)	5.5)	_	_	1.65		
Input leakage current	I _{IN}	$V_{IN} = V_{CC}$ or GND		5.5		_	±0.1	_	±1.0	μΑ	
Quiescent supply current	Icc	$V_{IN} = V_{CC}$ or GND		5.5	_	_	4.0	_	40.0	μА	

Note: This spec indicates the capability of driving 50 Ω transmission lines.

One output should be tested at a time for a 10 ms maximum duration.





Timing Requirements (input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition	Ta = 25°C	Ta = -40 to 85°C	Unit	
			V _{CC} (V)	Limit	Limit	
Minimum pulse width	t _{W (L)}		3.3 ± 0.3	8.0	8.0	20
(CK)	t _{W (H)}	_	5.0 ± 0.5	5.0	5.0	ns
Minimum pulse width	4		3.3 ± 0.3	7.0	7.0	20
(CLR , PR)	t _{W (L)}	_	5.0 ± 0.5	5.0	5.0	ns
Minimum oot un timo	4		3.3 ± 0.3	9.0	9.0	20
Minimum set-up time	t _s	_ (5.0 ± 0.5	5.0	5.0	ns
Minimum hold time	4.		3.3 ± 0.3	0.0	0.0	20
Minimum noid time	t _h	_ (()	5.0 ± 0.5	0.0	0.0	ns
Minimum removal time			3.3 ± 0.3	3.0	3.0	20
(CLR, PR)	t _{rem}	- 4(>>	5.0 ± 0.5	2.0	2.0	ns

AC Characteristics (C_L = 50 pF, R_L = 500 Ω , input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition Ta = 25°C					Unit		
	•		V _{CC} (V)	Min	Тур. (Max	Min	Max	
Propagation delay time	t _{pLH}	-	3.3 ± 0.3	_	8.2	13.9	1.0	16.0	ns
(CK-Q, \overline{Q})	t _{pHL}		5.0 ± 0.5		6.1	8.7	1.0	10.0	
Propagation delay time	t _{pLH}		3.3 ± 0.3		8.5	14.4	1.0	16.6	ns
$(\overline{CLR}, \overline{PR}-Q, \overline{Q})$	t _{pHL}		5.0 ± 0.5		6.4	9.1	1.0	10.5	110
Maximum clock	f		3.3 ± 0.3	55	120		55		MHz
frequency	f _{max}		5.0 ± 0.5	100	160	_	100	_	IVIITZ
Input capacitance	C _{IN}	<u> </u>	169	> -	5	10	_	10	pF
Power dissipation capacitance	C _{PD} (Note)				82		_	_	pF

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

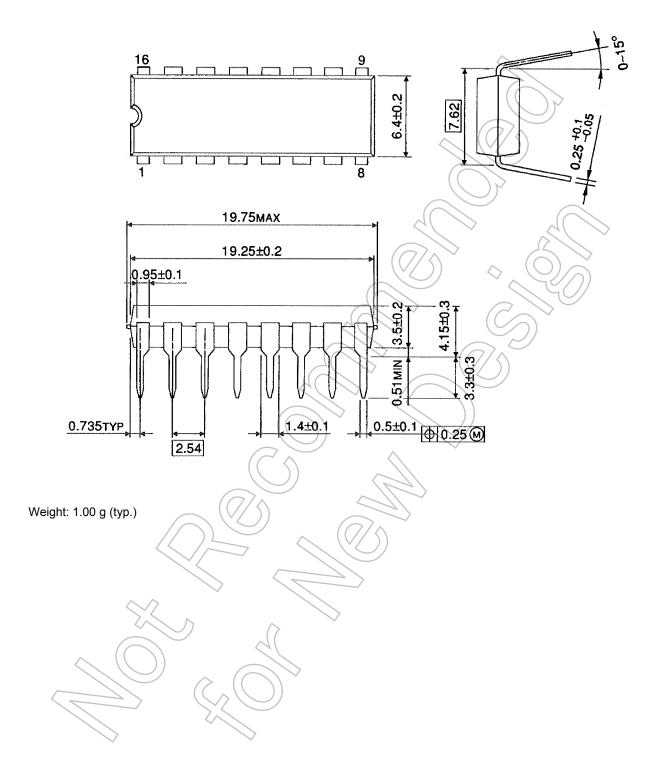
Average operating current can be obtained by the equation:

 I_{CC} (opr) = $C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/2$ (per F/F)



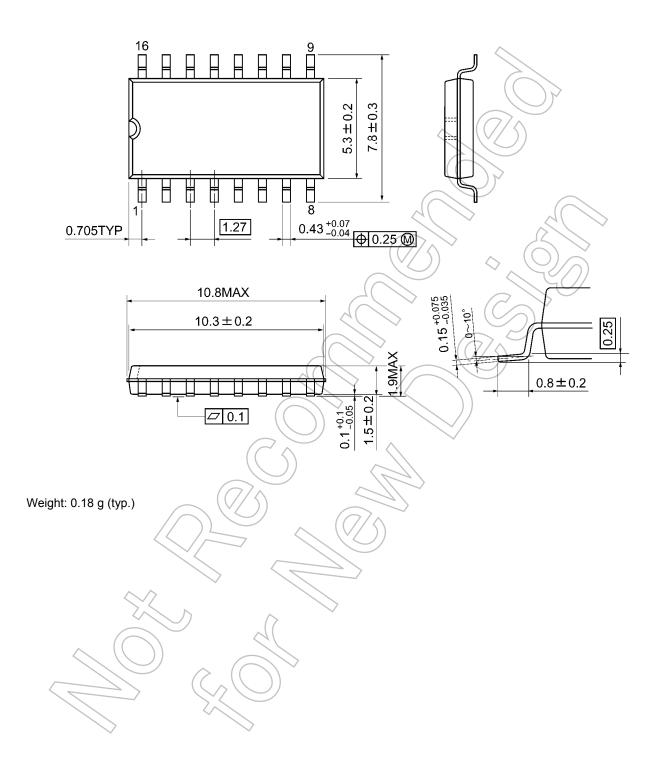
Package Dimensions

DIP16-P-300-2.54A Unit: mm



Package Dimensions

SOP16-P-300-1.27A Unit: mm



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